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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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### DATA SHEET

# **RENESAS** COMPOUND FIELD EFFECT POWER TRANSISTOR

# μ**ΡΑ1523Β**

#### P-CHANNEL POWER MOS FET ARRAY SWITCHING INDUSTRIAL USE

#### DESCRIPTION

The  $\mu$ PA1523B is P-channel Power MOS FET Array that built in 4 circuits designed for solenoid, motor and lamp driver.

#### FEATURES

- Full Mold Package with 4 Circuits
- -4 V driving is possible
- Low On-state Resistance R<sub>DS(on)1</sub> = 0.8 Ω MAX. (@V<sub>GS</sub> = -10 V, I<sub>D</sub> = -1 A) R<sub>DS(on)2</sub> = 1.3 Ω MAX. (@V<sub>GS</sub> = -4 V, I<sub>D</sub> = -1 A)
- Low Input Capacitance Ciss = 190 pF TYP.

#### ORDERING INFORMATION

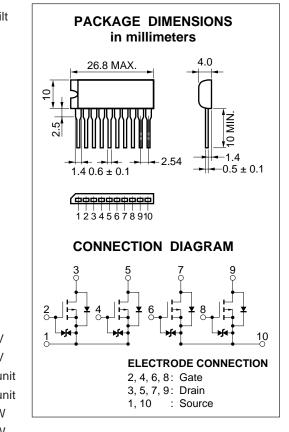
Type Number	Package
μPA1523BH	10 Pin SIP

#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage (Vgs = 0)	Vdss	-60	V	
Gate to Source Voltage ( $V_{DS} = 0$ )	VGSS(AC)	∓20	V	
Drain Current (DC)	in Current (DC) ID(DC)			
Drain Current (pulse)	D(pulse) *	I ∓8.0	A/uni	
Total Power Dissipation	Pt1 *2	28	W	
Total Power Dissipation	Pt2 *3	3.5	W	
Channel Temperature	Тсн	150	°C	
Storage Temperature	Tstg	–55 to + 150	°C	
Single Avalanche Current	las * <b>4</b>	-2.0	А	
Single Avalanche Energy	Eas *4	0.4	mJ	

\*1 PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

**\*3** 4 Circuits, T<sub>A</sub> = 25 °C



\*4 Starting TcH = 25 °C, VDD = -30 V, Vgs = -20 V  $\rightarrow 0$ , Rg = 25  $\Omega$ , L = 100  $\mu$ H

Build-in Gate Diodes are for protection from static electricity in handing. In case high voltage over V<sub>GSS</sub> is applied, please append gate protection circuits.

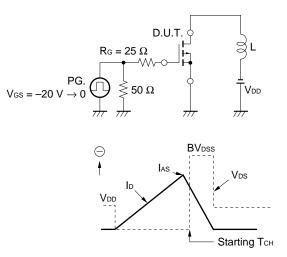
\*2 4 Circuits, Tc = 25 °C

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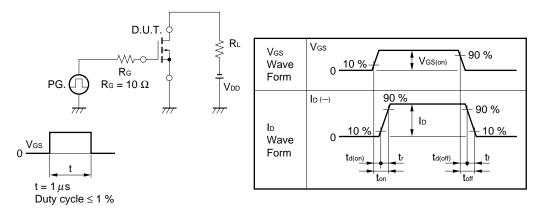
#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Leakage Current	loss	$V_{DS} = -60 V, V_{GS} = 0$			-10	μΑ
Gate Leakage Current	lgss	$V_{GS} = \mp 20 \text{ V}, \text{ V}_{DS} = 0$			<b>∓10</b>	μΑ
Gate Cutoff Voltage	VGS(off)	$V_{DS} = -10 \text{ V}, \text{ ID} = -1.0 \text{ mA}$	-1.0		-2.0	V
Forward Transfer Admittance	Y <sub>fs</sub>	$V_{DS} = -10 V, I_D = -1.0 A$	0.8			S
Drain to Source ON-Resistance	RDS(on)1	$V_{GS} = -10 \text{ V}, \text{ Id} = -1.0 \text{ A}$		0.5	0.8	Ω
Drain to Source ON-Resistance	RDS(on)2	$V_{GS} = -4.0 \text{ V}, \text{ Id} = -1.0 \text{ A}$		0.8	1.3	Ω
Input Capacitance	Ciss	$V_{DS} = -10 V$ , $V_{GS} = 0$ , f = 1.0 MHz		190		pF
Output Capacitance	Coss			115		pF
Reverse Transfer Capacitance	Crss			43		pF
Turn-on Delay Time	td(on)	$I_D = -1.0 \text{ A}, \text{ V}_{GS(on)} = -10 \text{ V},$		8		ns
Rise Time	tr	$V_{DD} \approx -30 \text{ V}, \text{ R}_{\text{L}} = 30 \Omega$		53		ns
Turn-off Delay Time	td(off)			400		ns
Fall Time	tr			230		ns
Total Gate Charge	QG	$V_{GS} = -10 \text{ V}, \text{ Id} = -2.0 \text{ A}, \text{ Vdd} = -48 \text{ V}$		10		nC
Gate to Source Charge	Qgs			1.1		nC
Gate to Drain Charge	Qgd			3.5		nC
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	IF = 2.0 A, VGS = 0		1.0		V
Reverse Recovery Time	trr	IF = 2.0 A, VGS = 0, di/dt = 50 A/µS		180		ns
Reverse Recovery Charge	Qrr			250		nC

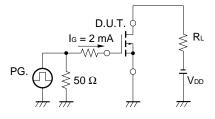
#### Test Circuit 1 Avalanche Capability



#### Test Circuit 2 Switching Time

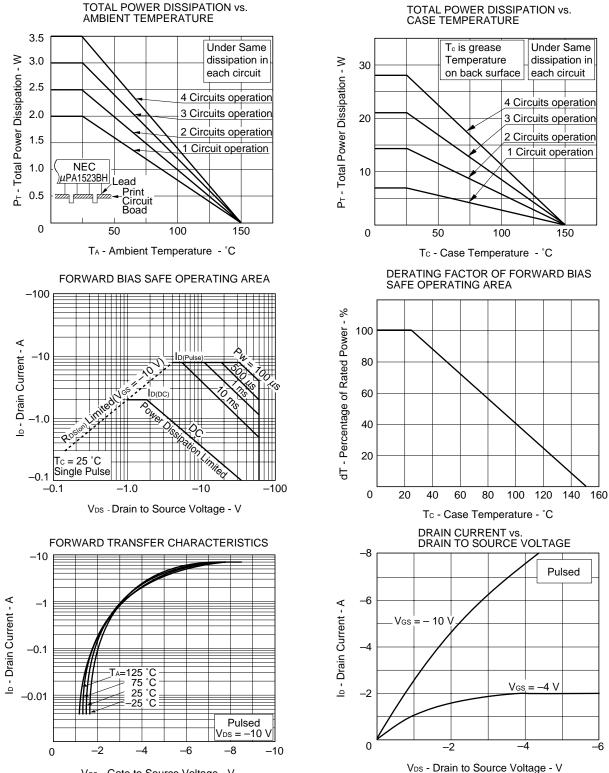


Test Circuit 3 Gate Charge

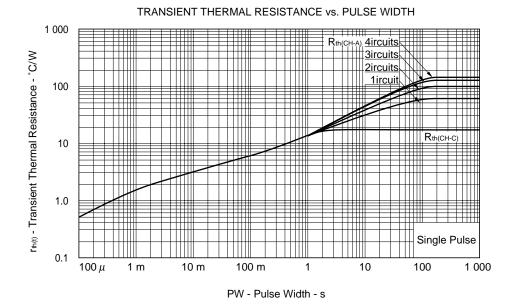


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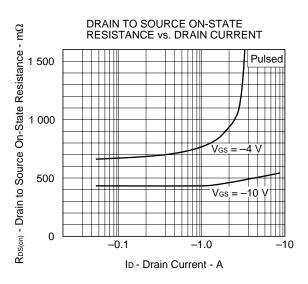




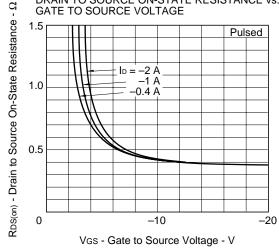
Vgs - Gate to Source Voltage - V



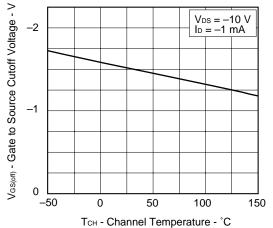
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT | yis | - Forward Transfer Admittance - S 100  $V_{DS} = -10 V$ Pulsed 10 -25 °C 25 °C 75 °C 125 °C TA = 1.0 0.1 -0.01 -0.1 -1.0 -10 ID - Drain Current - A



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE



-16

-14

-12

-10

-8

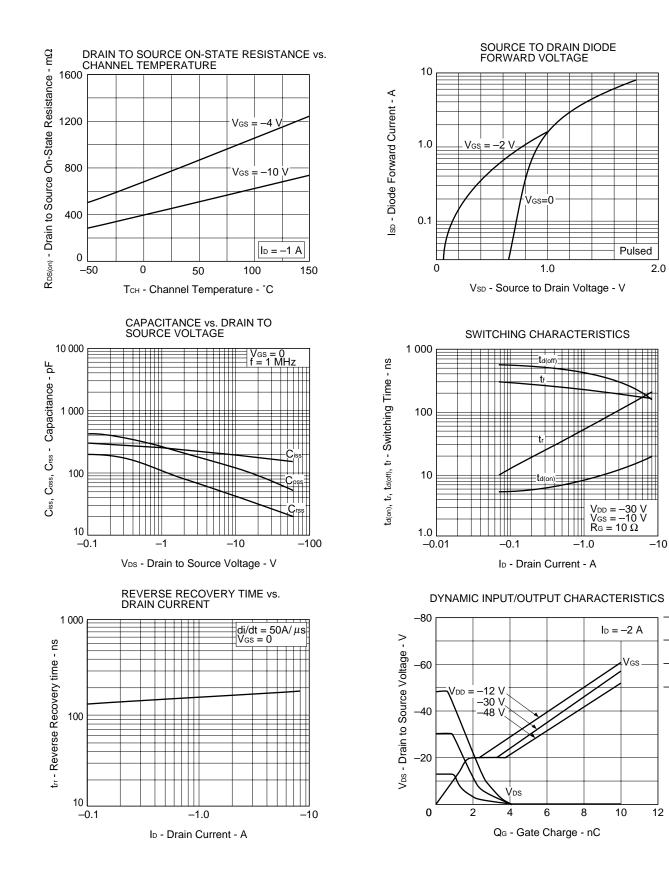
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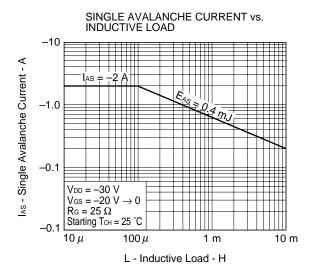
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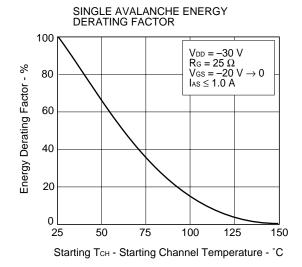
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Ves - Gate to Source Voltage







#### REFERENCE

Document Name	Document No.
NEC semiconductor for device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Semiconductor device package manual	C10943X
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E
Power MOS FET features and application switching power supply	TEA-1034
Application circuits using Power MOS FET	TEA-1035
Safe operating area of Power MOS FET	TEA-1037

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

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M4 94.11